

Standard Recovery Diodes (Stud Version), 150 A



DO-205AA (DO-8)

FEATURES

- Alloy diode
- High current carrying capability
- High surge current capabilities
- Stud cathode and stud anode version
- RoHS compliant
- Designed and qualified for industrial level



TYPICAL APPLICATIONS

- Battery chargers
- Welders
- Machine tool controls
- High power drives
- Medium traction applications
- Freewheeling diodes

PRODUCT SUMMARY

$I_{F(AV)}$	150 A
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MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		150	A
	T_C	150	°C
$I_{F(RMS)}$		235	A
I_{FSM}	50 Hz	3570	A
	60 Hz	3740	
I^2t	50 Hz	64	kA ² s
	60 Hz	58	
V_{RRM}	Range	100 to 600	V
T_J		- 40 to 200	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = 175\text{ °C}$ mA
45L(R) 150K(R) 150KS(R)	10	100	200	35
	20	200	300	
	30	300	400	
	40	400	500	
	60	600	720	

45L(R), 150K(R), 150KS(R) Series

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(Stud Version), 150 A



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			150	A
					150	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 142 °C case temperature			235	A
Maximum peak, one cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	3570	
		t = 8.3 ms			3740	
		t = 10 ms	100 % V _{RRM} reapplied		3000	
		t = 8.3 ms			3140	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		64	kA ² s
		t = 8.3 ms			58	
		t = 10 ms	100 % V _{RRM} reapplied		45	
		t = 8.3 ms			41	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			640	kA ² √s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J maximum			0.67	V
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J = T _J maximum			0.83	
Low level value of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J maximum			1.42	mΩ
High level value of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J = T _J maximum			0.91	
Maximum forward voltage drop	V _{FM}	I _{pk} = 471 A, T _J = 25 °C, t _p = 10 ms sinusoidal wave			1.33	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		- 40 to 200	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.25	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.10	
Mounting torque 45L	minimum	Not lubricated threads	14.1 (125)	N · m (lbf · in)
	maximum		17.0 (150)	
	minimum	Lubricated threads	12.2 (108)	
	maximum		15.0 (132)	
Mounting torque 150K 150KS	minimum	Not lubricated threads	11.3 (100)	N · m (lbf · in)
	maximum		14.1 (125)	
	minimum	Lubricated threads	9.5 (85)	
	maximum		12.5 (110)	
Approximate weight			100	g
			3.5	oz.
Case style	45L	See dimensions - link at the end of datasheet	DO-205AC (DO-30)	
	150K-A		DO-205AA (DO-8)	
	150KS		B-42	



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(Stud Version), 150 A

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ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.031	0.023	$T_J = T_J \text{ maximum}$	K/W
120°	0.038	0.040		
90°	0.048	0.053		
60°	0.071	0.075		
30°	0.120	0.121		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

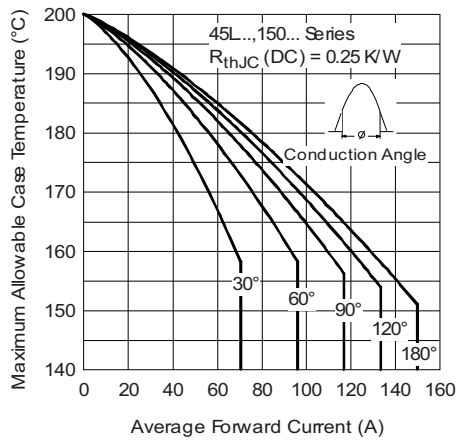


Fig. 1 - Current Ratings Characteristics

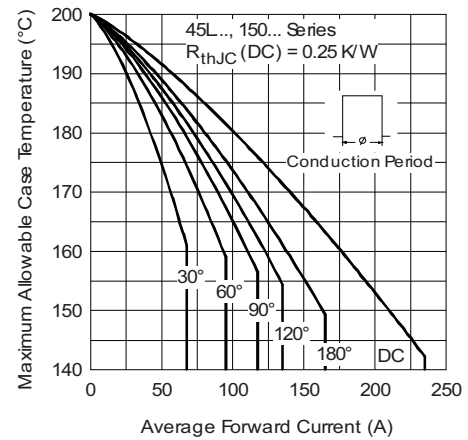


Fig. 2 - Current Ratings Characteristics

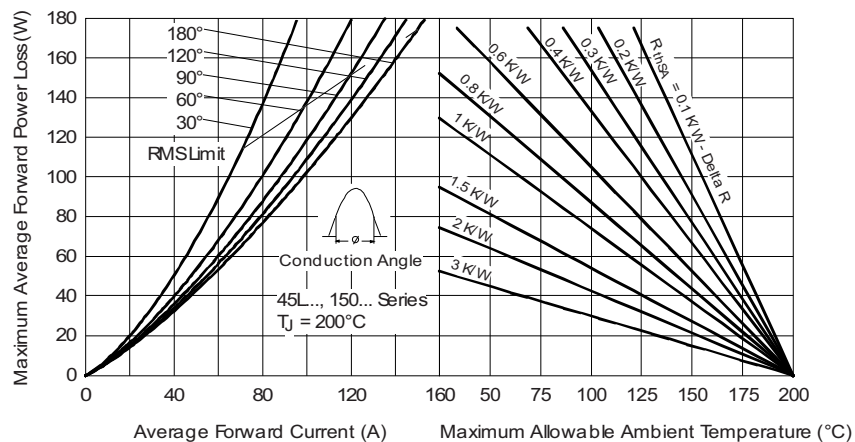


Fig. 3 - Forward Power Loss Characteristics

45L(R), 150K(R), 150KS(R) Series

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Standard Recovery Diodes
(Stud Version), 150 A

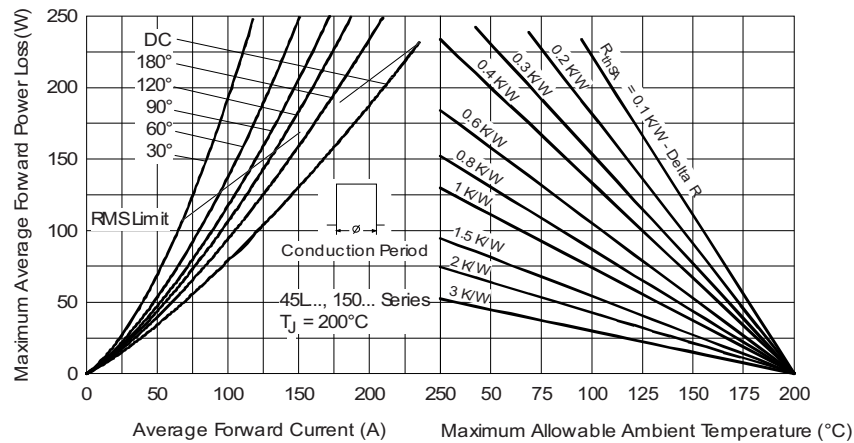


Fig. 4 - Forward Power Loss Characteristics

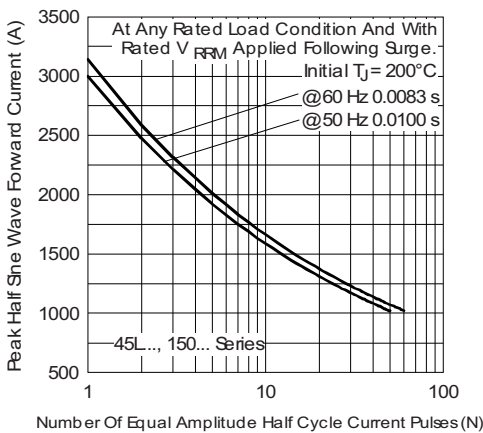


Fig. 5 - Maximum Non-Repetitive Surge Current

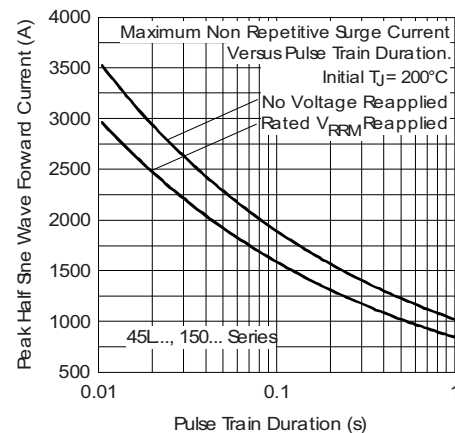


Fig. 6 - Maximum Non-Repetitive Surge Current

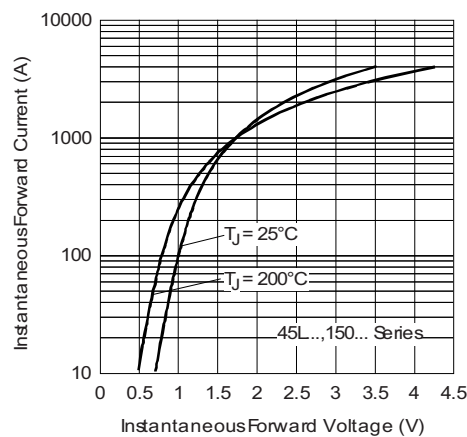


Fig. 7 - Forward Voltage Drop Characteristics



45L(R), 150K(R), 150KS(R) Series

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(Stud Version), 150 A

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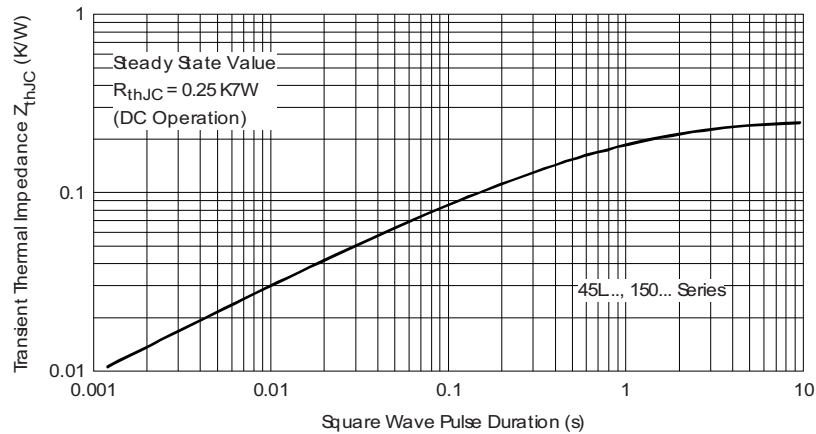


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLES

Device code

45	L	R	60
1	2	3	4

- 1** - 45 = Standard version
- 2** - L = Essential part number
- 3** - R = Stud reverse polarity (anode to stud)
None = Stud normal polarity (cathode to stud)
- 4** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

Device code

15	0	K	R	60	A
1	2	3	4	5	6

- 1** - 15 = Essential part number
- 2** - 0 = Standard device
- 3** - Case style:
K = DO-205AA (DO-8)
KS = B-42
- 4** - R = Stud reverse polarity (anode to stud)
None = Stud normal polarity (cathode to stud)
- 5** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 6** - A = Essential part number for 150K (omitted for 150KS)

Note: For metric device M12 x 1.75 contact factory

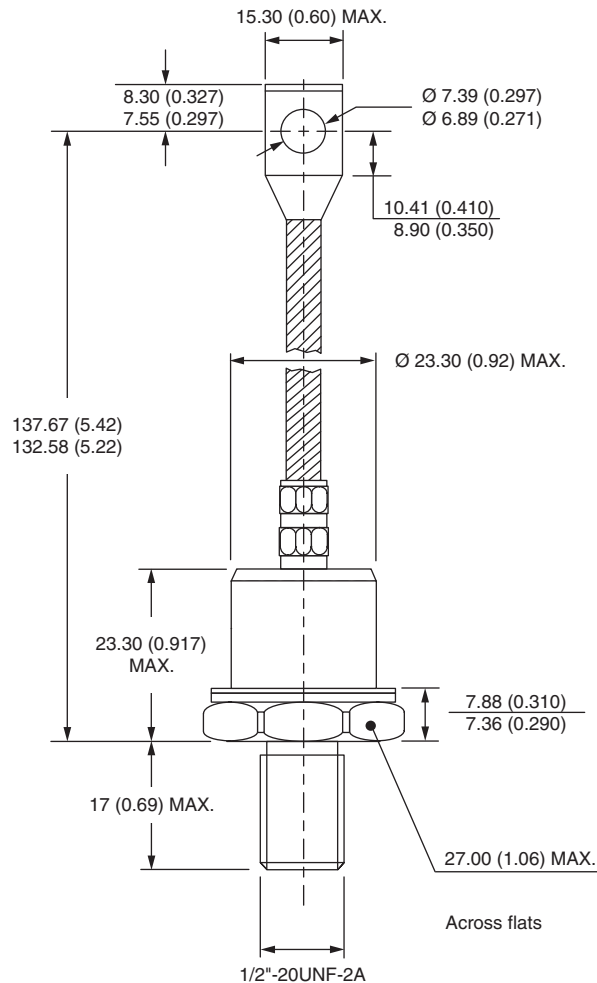
LINKS TO RELATED DOCUMENTS

Dimensions

<http://www.vishay.com/doc?95314>

DO-205AC (DO-30), DO-205AA (DO-8) and B-42 for 45L(R), 150K(R) and 150KS(R) Series

DIMENSIONS FOR 45L(R) SERIES - DO-205AC (DO-30) in millimeters (inches)



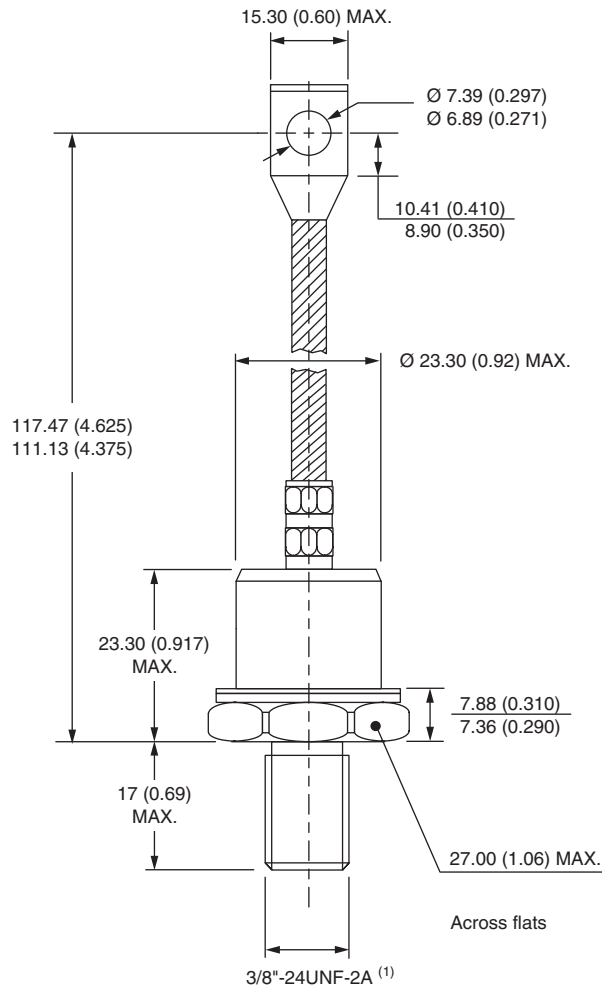
Outline Dimensions



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DO-205AC (DO-30), DO-205AA (DO-8)
and B-42 for 45L(R), 150K(R) and 150KS(R) Series

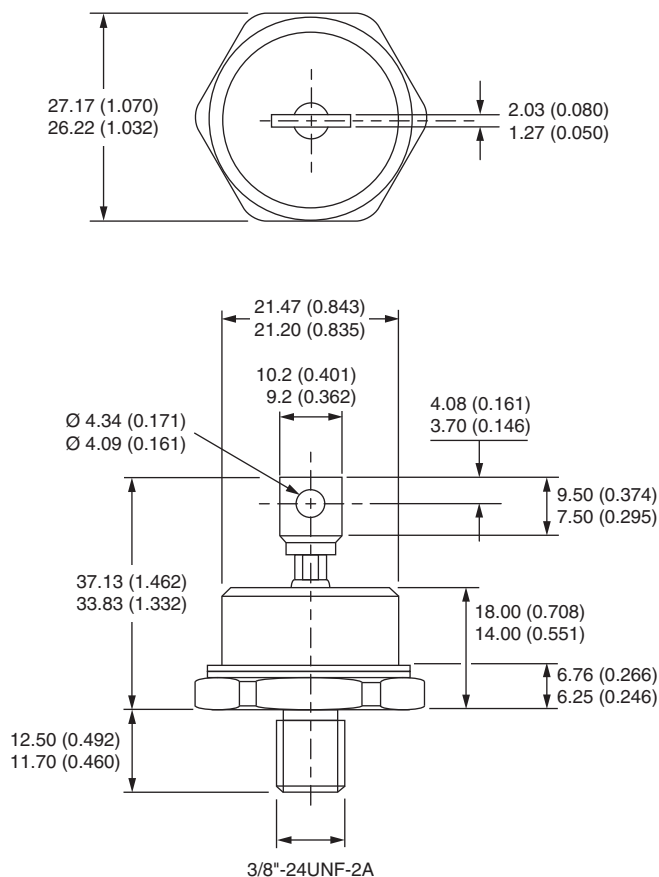
DIMENSIONS FOR 150K(R) SERIES - DO-205AA (DO-8) in millimeters (inches)



Note

⁽¹⁾ For metric device M12 x 1.75 contact factory

DIMENSIONS FOR 150KS(R) SERIES - B-42 in millimeters (inches)





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